

LETTERS TO THE EDITOR

EQUATION FOR NONEQUILIBRIUM SURFACE TENSION COMPONENTS

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The constant area and the variable frequency (ω) in the measurement process make the method of [1] useful for the study of surface tension (γ) at any deviation from equilibrium, independent of frequency. Let Γ_q be the equilibrium specific surface extensive parameters (for example, the density of adsorbed particles), and μ_q be the corresponding intensive parameters in the phases near their boundaries (the chemical potentials of the particles). Let [...] denote a row, column, or matrix (m by m or m by h), depending on whether it encloses either one of the indices p(q) or s(r), or both of them - p(q) and s(r); r, q = 1, ..., h; s, p = 1, ..., m; $[\Gamma_q] = \{\Gamma_1, \dots, \Gamma_h\}$ is a row. The Gibbs equation becomes $\Delta\gamma_0 = [\Gamma_q][\Delta\mu_r]$. Let m of the Γ_c be independent, $m \leq h$. If $\tilde{\Gamma}_s$ are the nonequilibrium values of the parameters, then at small $|\Gamma_s - \tilde{\Gamma}_s|$, $[d\tilde{\Gamma}_s/dt] = [k_{sp}][\Gamma_s - \tilde{\Gamma}_s]$ is valid. The surface kinetics matrix $K = [k_{sp}]$ characterizes the rates of adsorption and conversion in the interphase layer.

I. Systems in which $\gamma = \gamma([\Gamma_p])$. Under nonequilibrium conditions, to small increments (complex amplitudes) in $\Delta\mu_r^v$ accomplished over a time t according to the relation $\mu_r = \mu_{r0} + \Delta\mu_r^v f_v(t - t_r)$, corresponds $\Delta\gamma^v = \Delta\gamma_0^v + \Delta\gamma_n^v$,

$$\Delta\gamma_n^v = [\Gamma_p][\partial\Gamma_s/\partial\mu_p]^{-1}[a_{sp}^v][\partial\Gamma_s/\partial\mu_q][\Delta\mu_r^v], \quad (1)$$

$A^v = [a_{sp}^v]$ is the nonequilibrium matrix. For $\mu_r = \mu_{r0} + \Delta\mu_r^v \exp i\omega t$,

$$[a_{sp}^v] = A^v = I - (i\omega I + K)^{-1}K, \quad (2)$$

where I is the unit matrix. For $h = m + 1$: $[\Gamma_p][\partial\Gamma_s/\partial\mu_p]^{-1}[\partial\Gamma_s/\partial\mu_h] - \Gamma_h = 0$.

II. Systems in which $\gamma = \gamma([\mu_q], [\Gamma_p])$. Example. Let the solution consist of one surface-active substance $\Gamma_1 = \Gamma$, $\mu_1 = \mu$, $d\Gamma/dt = k[\Gamma - \tilde{\Gamma}]$ and let the rest of the electrolyte be of any composition. If ϵ and ψ are the charge and potential of the electrode ($\epsilon + z_1\Gamma_1 + \dots + z_m\Gamma_m = 0$, where z_s are the charges of the particles in the solution) and $\psi = \psi_0 + \Delta\psi \exp i\omega t$, then for a given ψ_0 ,

$$\Delta\gamma^\omega = \Delta\gamma_0^\omega + \Delta\gamma_n^\omega = \left[-\epsilon + \Gamma \left(\frac{\partial\Gamma}{\partial\psi} / \frac{\partial\Gamma}{\partial\mu} \right) \frac{\omega}{\gamma\omega^2 + k^2} e^{i \arctg(k/\omega)} \right] \Delta\psi. \quad (3)$$

If the diffusion rate of particles for which $s = 1$ is also important (coefficient D and concentration c in the solution), then

$$\Delta\gamma^\omega = \left[-\epsilon + \Gamma \left(\frac{\partial\Gamma}{\partial\psi} / \frac{\partial\Gamma}{\partial\mu} \right) \frac{(\lambda + \kappa)^2 + \kappa(1 + \kappa) + i(\lambda + \kappa)}{(\lambda + \kappa)^2 + (1 + \kappa)^2} \right] \Delta\psi, \quad (4)$$

$\lambda = \omega/k$, and $\kappa = (\partial\Gamma/\partial c)\sqrt{\omega/2D}$. From Eqs. (1)-(4) it follows that with an increase in $|\Delta\gamma|$ the displacement of the zero (minimum) of the curve ψ_0 from one point on the zero line to another occurs by a rise over the zero line at intermediate values of ω . This is actually observed (Pt in 1 N H_2SO_4 , a sharp rise of the zeros +0.21, +0.10, and +0.08 V NHE during the transition from 1 to 5 kHz; oscillograms of $|\Delta\gamma| - \psi_0$ were recorded simultaneously at both frequencies).

LITERATURE CITED

1. A. Ya. Gokhshtein, *Zavod. Lab.*, **32**, 815 (1966); *Élektrokhiimiya*, **2**, 1318 (1966); *Dokl. Akad. Nauk SSSR*, **174**, 394 (1967); *Fiz. i Tekh. Poluprov.*, **1**, 1486, 1787 (1967).